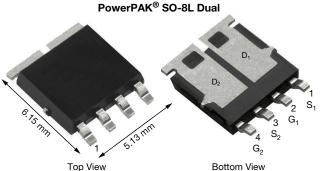
## SQJB40EP

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SHA

**Vishay Siliconix** 

# Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET



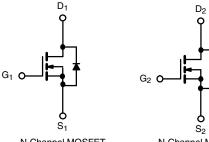
	Dottom view		
PRODUCT SUMMARY			
V <sub>DS</sub> (V)	40		
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 V$	0.008		
$R_{DS(on)}$ ( $\Omega$ ) at $V_{GS}$ = 4.5 V	0.011		
I <sub>D</sub> (A) per leg	30		
Configuration	Dual		

#### **FEATURES**

- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 qualified
- 100 %  $R_q$  and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



RoHS COMPLIANT HALOGEN FREE



N-Channel MOSFET

N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJB40EP (for detailed order number please see <u>www.vishay.com/doc?79771</u> )

PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V <sub>DS</sub>	40	- v	
Gate-source voltage		V <sub>GS</sub>	± 20		
Continuous drain current	T <sub>C</sub> = 25 °C ª	I	30		
	T <sub>C</sub> = 125 °C	ID	29		
Continuous source current (diode conduction) a		I <sub>S</sub>	30	А	
Pulsed drain current <sup>b</sup>		I <sub>DM</sub>	80		
Single pulse avalanche current	L = 0.1 mH	I <sub>AS</sub>	22		
Single pulse avalanche energy	L = 0.1 MH	E <sub>AS</sub>	24	mJ	
Maximum power dissipation <sup>b</sup>	T <sub>C</sub> = 25 °C	D	34	w	
	T <sub>C</sub> = 125 °C	P <sub>D</sub>	11		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C	
Soldering recommendations (peak temperature) d		-	260	-0	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction to ambient	PCB mount <sup>c</sup>	R <sub>thJA</sub>	85	°C/W
Junction to case (drain)		R <sub>thJC</sub>	4.3	C/W

#### Notes

a. Package limited

b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

c. When mounted on 1" square PCB (FR4 material)

d. See solder profile (<u>www.vishay.com/doc?73257</u>). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

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SQJB40EP

PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V <sub>DS</sub>	$V_{GS}$ = 0 V, $I_D$ = 250 $\mu$ A		40	-	-	v
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	= V <sub>GS</sub> , I <sub>D</sub> = 250 μA	1.2	1.8	2.5	v
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, $V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{GS} = 0 V$	0 V V <sub>DS</sub> = 40 V		-	1	
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 175 °C	-	-	250	
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V	$V_{DS} \ge 5 V$	20	-	-	А
	- ()	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 8 A	-	0.0063	0.0080	
Drain actures an state registerios 3	P	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 8 A, T <sub>J</sub> = 125 °C	-	-	0.0117	Ω
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 8 A, T <sub>J</sub> = 175 °C	-	-	0.0138	
		V <sub>GS</sub> = 4.5 V	I <sub>D</sub> = 5 A	-	0.0083	0.0110	
Forward transconductance b	<b>g</b> fs	V <sub>DS</sub>	= 15 V, I <sub>D</sub> = 8 A	-	48	-	S
Dynamic <sup>b</sup>					•		
Input capacitance	C <sub>iss</sub>			-	1415	1900	
Output capacitance	Coss	$V_{GS} = 0 V$	V <sub>DS</sub> = 25 V, f = 1 MHz	-	935	1300	pF
Reverse transfer capacitance	C <sub>rss</sub>			-	45	65	
Total gate charge <sup>c</sup>	Qg			-	20	35	
Gate-source charge <sup>c</sup>	Q <sub>gs</sub>	$V_{GS} = 10 V$	$V_{DS} = 20 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	-	4.3	-	nC
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>			-	2.5	-	
Gate resistance	Rg	f = 1 MHz		0.30	0.74	1.20	Ω
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>		$V_{DD} = 20 \text{ V}, \text{ R}_1 = 4 \Omega$		7	15	
Rise time <sup>c</sup>	t <sub>r</sub>	V <sub>DD</sub>			20	35	- ns
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 5 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		-	18	35	
Fall time <sup>c</sup>	t <sub>f</sub>			-	15	25	
Source-Drain Diode Ratings and Charac	teristics <sup>b</sup>						
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	80	А
Forward voltage	V <sub>SD</sub>	l <sub>F</sub> =	= 8 A, V <sub>GS</sub> = 0 V	-	0.803	1.200	V
Body diode reverse recovery time	t <sub>rr</sub>			-	50	100	ns
Body diode reverse recovery charge	Q <sub>rr</sub>	]	A di/dt 100 A /	-	60	120	nC
Reverse recovery fall time	ta	ι <sub>F</sub> = 8 .	A, di/dt = 100 A/µs	-	27	-	
Reverse recovery rise time	t <sub>b</sub>	1		-	23	-	ns
Body diode peak reverse recoverycurrent	I <sub>RM(REC)</sub>			-	-2.3	-	Α

#### Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

b. Guaranteed by design, not subject to production testing

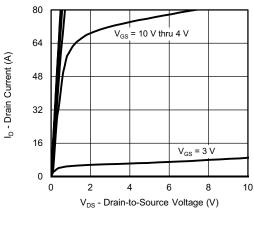
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

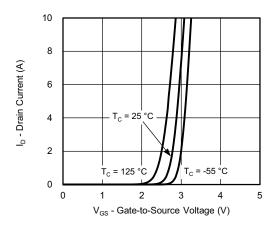
2



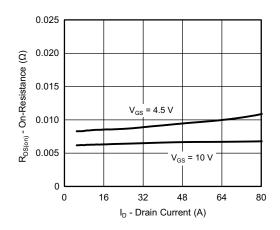
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



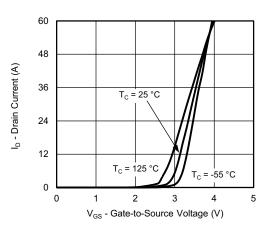
**Output Characteristics** 



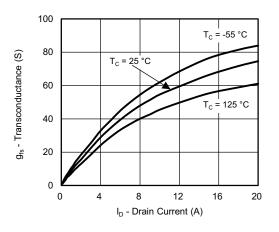
**Transfer Characteristics** 

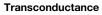


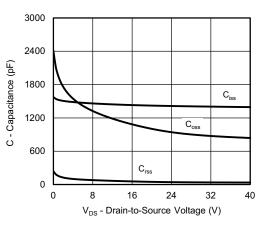
**On-Resistance vs. Drain Current** 



**Transfer Characteristics** 







Capacitance

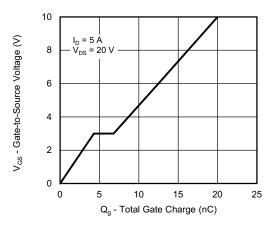
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3 s. contact: automostechsu Document Number: 68550

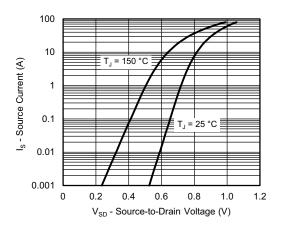
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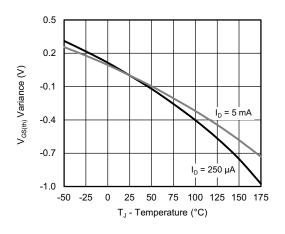
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



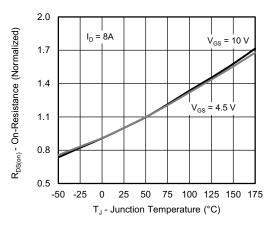
Gate Charge



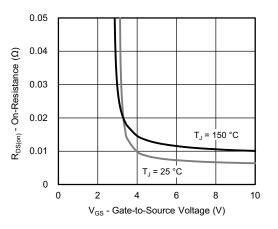
Source Drain Diode Forward Voltage



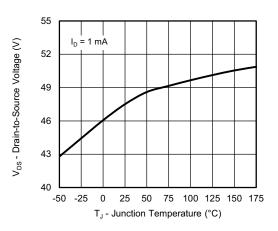
**Threshold Voltage** 



**On-Resistance vs. Junction Temperature** 



On-Resistance vs. Gate-to-Source Voltage



**Drain Source Breakdown vs. Junction Temperature** 

4

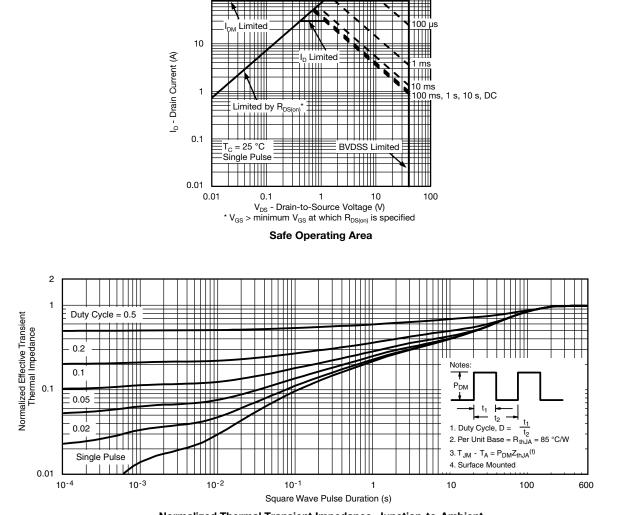
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### **THERMAL RATINGS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)

100



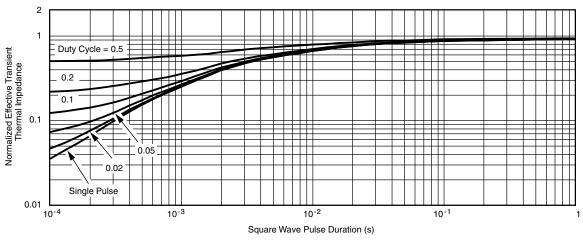
Normalized Thermal Transient Impedance, Junction-to-Ambient

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### **THERMAL RATINGS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

#### Note

• The characteristics shown in the two graphs

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- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

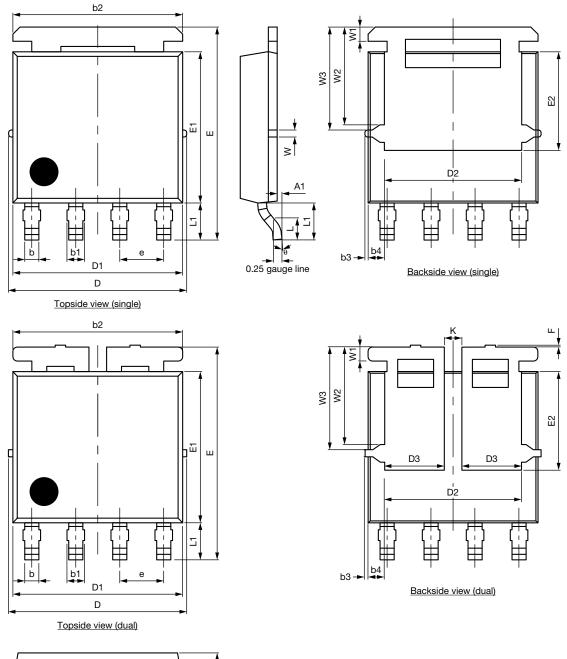
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

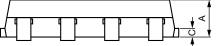
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?68550">www.vishay.com/ppg?68550</a>.

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## **Package Information**



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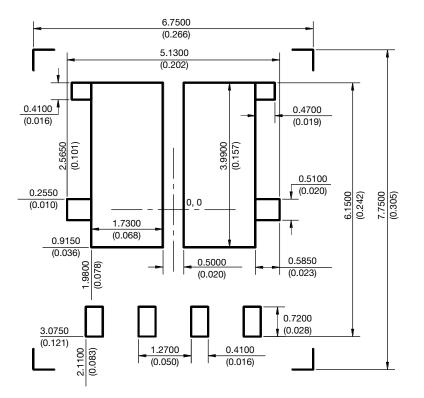
DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	MIN. NOM.		
А	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
К		0.51			0.020		
W		0.23			0.009		
W1	0.41			0.016			
W2		2.82			0.111		
W3		2.96		0.117			
θ	0°	-	10°	0°	-	10°	

Note

• Millimeters will govern



#### **RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL**



Recommended Minimum Pads Dimensions in mm (inches) Keep-out 6.75 (0.266) x 7.75 (0.305)

Revision: 07-Feb-12



Vishay

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